NSN 5961-01-076-7723

A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-076-7723 **Overall Length:** 0.800 inches **Overall Diameter:** 0.424 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-4 **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.430 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 working peak reverse voltage **Current Rating Per Characteristic:** 12.00 amperes forward current, total rms megahertz **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: